2N7002L, 2V7002L

Small Signal MOSFET

60 V, 115 mA, N-Channel SOT-23

Features

- 2V Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable (2V7002L)
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|--|---|---------------------|------------|
| Drain-Source Voltage | V _{DSS} | 60 | Vdc |
| Drain-Gate Voltage (R_{GS} = 1.0 M Ω) | V _{DGR} | 60 | Vdc |
| Drain Current – Continuous $T_C = 25^{\circ}C$ (Note 1) $T_C = 100^{\circ}C$ (Note 1) – Pulsed (Note 2) | I _D I _D I _{DM} | ±115 ±75 ±800 | mAdc |
| Gate–Source Voltage – Continuous – Non–repetitive (t _p ≤ 50 μs) | V _{GS} V _{GSM} | ±20 ±40 | Vdc Vpk |

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Мах | Unit |
|---|------------------------------------|-------------------|---------------------|
| Total Device Dissipation FR–5 Board (Note 3) T _A = 25°C Derate above 25°C Thermal Resistance, Junction–to–Ambient | P _D R _{θJA} | 225 1.8 556 | mW mW/°C °C/W |
| Total Device Dissipation (Note 4) Alumina Substrate, T _A = 25°C Derate above 25°C Thermal Resistance, Junction-to-Ambient | P _D R _{θJA} | 300 2.4 417 | mW mW/°C °C/W |
| Junction and Storage Temperature | T _J , T _{stg} | –55 to +150 | °C |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. The Power Dissipation of the package may result in a lower continuous drain current.

2. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.

3. FR-5 = 1.0 x 0.75 x 0.062 in.

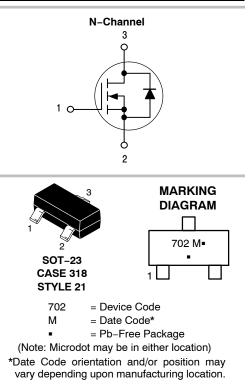
4. Alumina = 0.4 x 0.3 x 0.025 in 99.5% alumina.



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| V _{(BR)DSS} | R _{DS(on)} MAX | I _D MAX |
|----------------------|-------------------------|--------------------|
| 60 V | 7.5 Ω @ 10 V, 500 mA | 115 mA |



ORDERING INFORMATION

| Device | Package | Shipping [†] | | |
|-------------|---------------------|-----------------------|--|--|
| 2N7002LT1G | | 3,000 Tape & Reel | | |
| 2N7002LT3G | SOT-23 (Pb-Free) | 10,000 Tape & Reel | | |
| 2N7002LT7G | | 3,500 Tape & Reel | | |
| 2V7002LT1G | | 3,000 Tape & Reel | | |
| 2V7002LT3G | SOT-23 (Pb-Free) | 10,000 Tape & Reel | | |
| 2N7002LT1H* | | 3,000 Tape & Reel | | |
| 2N7002LT7H* | | 3,500 Tape & Reel | | |

+For information on tape and reel specifications, including part orientation and tape sizes, please

refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*Not for new design.

2N7002L, 2V7002L

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

| C | Symbol | Min | Тур | Max | Unit | |
|--|---|----------------------|--------|---------------|-------------|------|
| OFF CHARACTERISTICS | | | | | | |
| Drain–Source Breakdown Volt (V_{GS} = 0, I _D = 10 μ Adc) | age | V _{(BR)DSS} | 60 | - | - | Vdc |
| Zero Gate Voltage Drain Curre $(V_{GS} = 0, V_{DS} = 60 \text{ Vdc})$ | ent $T_J = 25^{\circ}C$ $T_J = 125^{\circ}C$ | I _{DSS} | - | | 1.0 500 | μAdc |
| Gate-Body Leakage Current, Forward (V _{GS} = 20 Vdc) | | I _{GSSF} | - | - | 100 | nAdc |
| Gate-Body Leakage Current, (V _{GS} = -20 Vdc) | I _{GSSR} | - | - | -100 | nAdc | |
| ON CHARACTERISTICS (Not | te 5) | | | | • | • |
| Gate Threshold Voltage (V _{DS} = V _{GS} , I _D = 250 μAdd | ;) | V _{GS(th)} | 1.0 | - | 2.5 | Vdc |
| $\begin{array}{l} On-State \ Drain \ Current \\ (V_{DS} \geq 2.0 \ V_{DS(on)}, \ V_{GS} = \end{array}$ | I _{D(on)} | 500 | - | _ | mA | |
| $\begin{array}{l} \text{Static Drain-Source On-State} \\ (\text{V}_{\text{GS}} = 10 \text{ Vdc}, \text{ I}_{\text{D}} = 500 \text{ m} \\ (\text{V}_{\text{GS}} = 5.0 \text{ Vdc}, \text{ I}_{\text{D}} = 50 \text{ m} \end{array}$ | V _{DS(on)} | | | 3.75 0.375 | Vdc | |
| Static Drain–Source On–State (V _{GS} = 10 V, I _D = 500 mAd | $T_{C} = 25^{\circ}C$ $T_{C} = 125^{\circ}C$ | r _{DS(on)} | - - | | 7.5 13.5 | Ohms |
| (V _{GS} = 5.0 Vdc, I _D = 50 m/ | Adc) $T_{C} = 25^{\circ}C$ $T_{C} = 125^{\circ}C$ | | - | | 7.5 13.5 | |
| Forward Transconductance $(V_{DS} \ge 2.0 V_{DS(on)}, I_D = 20)$ | 0 mAdc) | 9FS | 80 | - | - | mS |
| DYNAMIC CHARACTERISTIC | CS | 11 | | | | |
| Input Capacitance (V _{DS} = 25 Vdc, V _{GS} = 0, f = 1.0 MHz) | | C _{iss} | - | - | 50 | pF |
| Output Capacitance (V _{DS} = 25 Vdc, V _{GS} = 0, f = 1.0 MHz) | | C _{oss} | - | - | 25 | pF |
| Reverse Transfer Capacitance $(V_{DS} = 25 \text{ Vdc}, V_{GS} = 0, f$ | C _{rss} | - | - | 5.0 | pF | |
| SWITCHING CHARACTERIS | TICS (Note 5) | | | | | |
| Turn-On Delay Time | $(V_{DD} = 25 \text{ Vdc}, I_D \cong 500 \text{ mAdc},$ | t _{d(on)} | - | - | 20 | ns |
| Turn-Off Delay Time | $R_{G} = 25 \Omega, R_{L} = 50 \Omega, V_{gen} = 10 V$ | t _{d(off)} | _ | - | 40 | ns |
| BODY-DRAIN DIODE RATIN | GS | | | | | |
| Diode Forward On–Voltage ($I_S = 11.5 \text{ mAdc}, V_{GS} = 0 \text{ V}$ | V _{SD} | - | - | -1.5 | Vdc | |
| Source Current Continuous (Body Diode) | | I _S | - | - | -115 | mAdo |
| | | 1 | | 1 | | |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 5. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2.0%.

 I_{SM}

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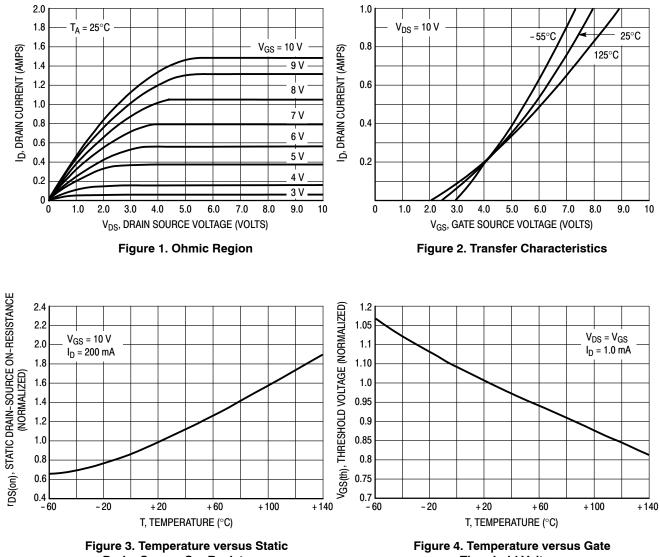
-800

mAdc

Source Current Pulsed

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TYPICAL ELECTRICAL CHARACTERISTICS

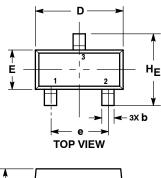


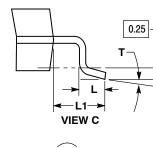
Drain-Source On-Resistance

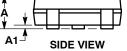
Threshold Voltage

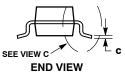
PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 **ISSUE AS**









NOTES: DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. CONTROLLING DIMENSION: MILLIMETERS.

MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF 3.

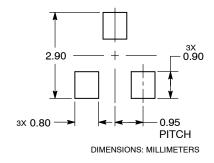
THE BASE MATERIAL. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. 4

| Hornoolono, on date bonno. | | | | | | |
|----------------------------|-------------|------|------|--------|-------|-------|
| | MILLIMETERS | | | INCHES | | |
| DIM | MIN | NOM | MAX | MIN | NOM | MAX |
| Α | 0.89 | 1.00 | 1.11 | 0.035 | 0.039 | 0.044 |
| A1 | 0.01 | 0.06 | 0.10 | 0.000 | 0.002 | 0.004 |
| b | 0.37 | 0.44 | 0.50 | 0.015 | 0.017 | 0.020 |
| С | 0.08 | 0.14 | 0.20 | 0.003 | 0.006 | 0.008 |
| D | 2.80 | 2.90 | 3.04 | 0.110 | 0.114 | 0.120 |
| Е | 1.20 | 1.30 | 1.40 | 0.047 | 0.051 | 0.055 |
| e | 1.78 | 1.90 | 2.04 | 0.070 | 0.075 | 0.080 |
| Г | 0.30 | 0.43 | 0.55 | 0.012 | 0.017 | 0.022 |
| L1 | 0.35 | 0.54 | 0.69 | 0.014 | 0.021 | 0.027 |
| HE | 2.10 | 2.40 | 2.64 | 0.083 | 0.094 | 0.104 |
| Т | 0° | | 10° | 0° | | 10° |

STYLE 21: PIN 1. GATE 2.

SOURCE 3. DRAIN

RECOMMENDED SOLDERING FOOTPRINT



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